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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

Applications of "[Embedded - Microcontrollers](#)"

Details

Product Status	Not For New Designs
Core Processor	M16C/60
Core Size	16-Bit
Speed	24MHz
Connectivity	I ² C, IEBus, UART/USART
Peripherals	DMA, WDT
Number of I/O	50
Program Memory Size	-
Program Memory Type	ROMless
EEPROM Size	-
RAM Size	10K x 8
Voltage - Supply (Vcc/Vdd)	2.7V ~ 5.5V
Data Converters	A/D 26x10b; D/A 2x8b
Oscillator Type	Internal
Operating Temperature	-20°C ~ 85°C (TA)
Mounting Type	Surface Mount
Package / Case	100-BQFP
Supplier Device Package	100-QFP (14x20)
Purchase URL	https://www.e-xfl.com/product-detail/renesas-electronics-america/m30620spfp-u5c

Table 1.2 Performance Outline of M16C/62P Group (M16C/62P, M16C/62PT)(100-pin version)

	Item	Performance	
		M16C/62P	M16C/62PT ⁽⁴⁾
CPU	Number of Basic Instructions	91 instructions	
	Minimum Instruction Execution Time	41.7ns(f(BCLK)=24MHz, VCC1=3.3 to 5.5V) 100ns(f(BCLK)=10MHz, VCC1=2.7 to 5.5V)	41.7ns(f(BCLK)=24MHz, VCC1=4.0 to 5.5V)
	Operating Mode	Single-chip, memory expansion and microprocessor mode	Single-chip
	Address Space	1 Mbyte (Available to 4 Mbytes by memory space expansion function)	1 Mbyte
	Memory Capacity	See Table 1.4 to 1.7 Product List	
Peripheral Function	Port	Input/Output : 87 pins, Input : 1 pin	
	Multifunction Timer	Timer A : 16 bits x 5 channels, Timer B : 16 bits x 6 channels, Three phase motor control circuit	
	Serial Interface	3 channels Clock synchronous, UART, I ² C bus ⁽¹⁾ , IEBus ⁽²⁾ 2 channels Clock synchronous	
	A/D Converter	10-bit A/D converter: 1 circuit, 26 channels	
	D/A Converter	8 bits x 2 channels	
	DMAC	2 channels	
	CRC Calculation Circuit	CCITT-CRC	
	Watchdog Timer	15 bits x 1 channel (with prescaler)	
	Interrupt	Internal: 29 sources, External: 8 sources, Software: 4 sources, Priority level: 7 levels	
	Clock Generation Circuit	4 circuits Main clock generation circuit (*), Subclock generation circuit (*), On-chip oscillator, PLL synthesizer (*)Equipped with a built-in feedback resistor.	
	Oscillation Stop Detection Function	Stop detection of main clock oscillation, re-oscillation detection function	
	Voltage Detection Circuit	Available (option ⁽⁵⁾)	Absent
Electric Characteristics	Supply Voltage	VCC1=3.0 to 5.5 V, VCC2=2.7V to VCC1 (f(BCLK)=24MHz) VCC1=2.7 to 5.5 V, VCC2=2.7V to VCC1 (f(BCLK)=10MHz)	VCC1=VCC2=4.0 to 5.5V (f(BCLK)=24MHz)
	Power Consumption	14 mA (VCC1=VCC2=5V, f(BCLK)=24MHz) 8 mA (VCC1=VCC2=3V, f(BCLK)=10MHz) 1.8μA (VCC1=VCC2=3V, f(XCIN)=32kHz, wait mode) 0.7μA (VCC1=VCC2=3V, stop mode)	14 mA (VCC1=VCC2=5V, f(BCLK)=24MHz) 2.0μA (VCC1=VCC2=5V, f(XCIN)=32kHz, wait mode) 0.8μA (VCC1=VCC2=5V, stop mode)
Flash memory version	Program/Erase Supply Voltage	3.3±0.3 V or 5.0±0.5 V	5.0±0.5 V
	Program and Erase Endurance	100 times (all area) or 1,000 times (user ROM area without block A and block 1) / 10,000 times (block A, block 1) ⁽³⁾	
Operating Ambient Temperature		-20 to 85°C, -40 to 85°C ⁽³⁾	T version : -40 to 85°C V version : -40 to 125°C
Package		100-pin plastic mold QFP, LQFP	

NOTES:

1. I²C bus is a registered trademark of Koninklijke Philips Electronics N. V.
2. IEBus is a registered trademark of NEC Electronics Corporation.
3. See **Table 1.8 and 1.9 Product Code** for the program and erase endurance, and operating ambient temperature.
In addition 1,000 times/10,000 times are under development as of Jul., 2005. Please inquire about a release schedule.
4. Use the M16C/62PT on VCC1=VCC2
5. All options are on request basis.

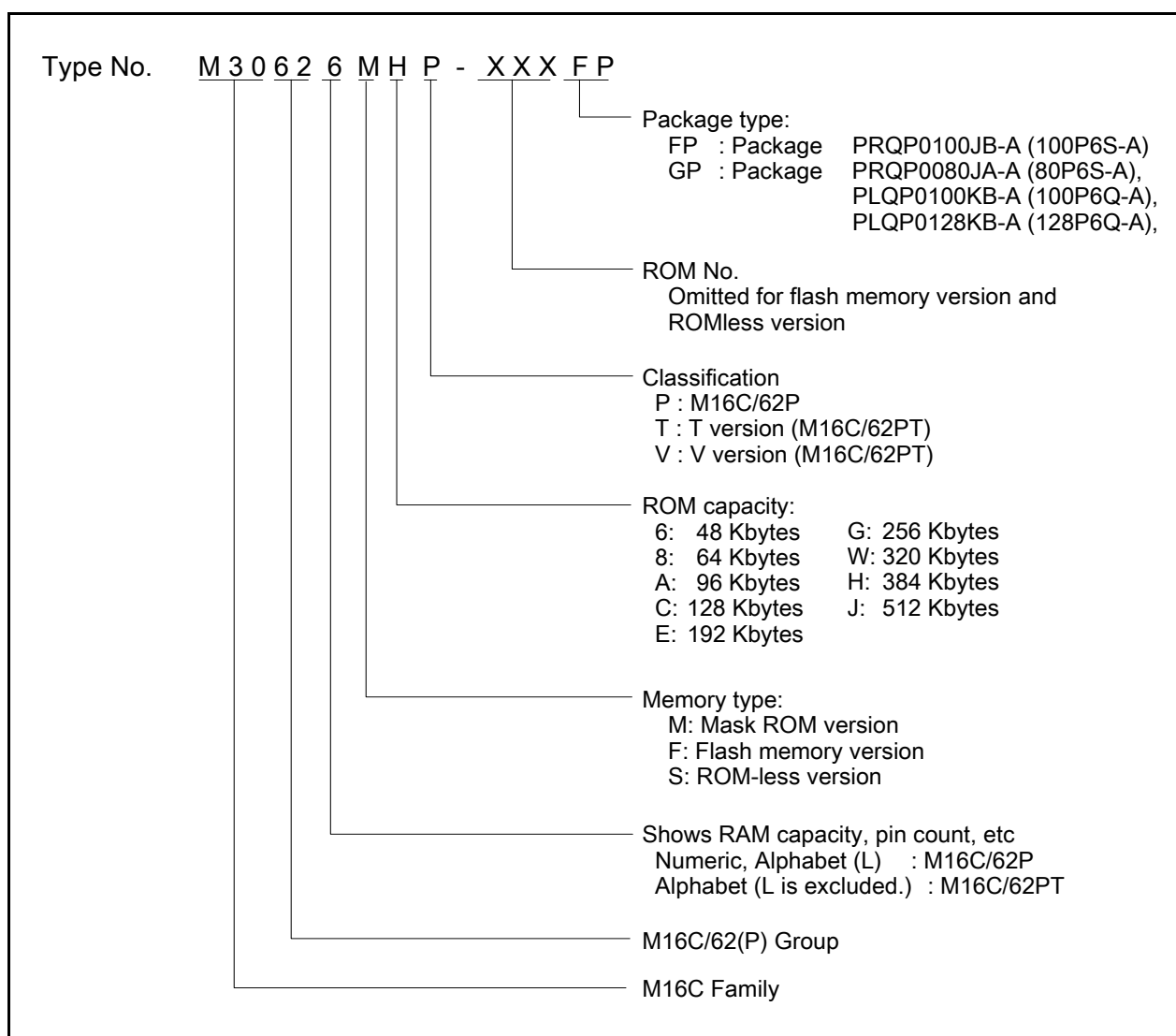


Figure 1.3 Type No., Memory Size, and Package

Table 1.8 Product Code of Flash Memory version and ROMless version for M16C/62P

	Product Code	Package	Internal ROM (User ROM Area Without Block A, Block 1)		Internal ROM (Block A, Block 1)		Operating Ambient Temperature
			Program and Erase Endurance	Temperature Range	Program and Erase Endurance	Temperature Range	
Flash memory Version	D3	Lead-included	100	0°C to 60°C	100	0°C to 60°C	-40°C to 85°C
	D5						-20°C to 85°C
	D7		1,000		10,000	-40°C to 85°C	-40°C to 85°C
	D9					-20°C to 85°C	-20°C to 85°C
	U3	Lead-free	100		100	0°C to 60°C	-40°C to 85°C
	U5					-20°C to 85°C	
	U7		1,000		10,000	-40°C to 85°C	-40°C to 85°C
	U9					-20°C to 85°C	-20°C to 85°C
ROM-less version	D3	Lead-included	—	—	—	—	-40°C to 85°C
	D5		—	—	—	—	-20°C to 85°C
	U3	Lead-free	—	—	—	—	-40°C to 85°C
	U5		—	—	—	—	-20°C to 85°C

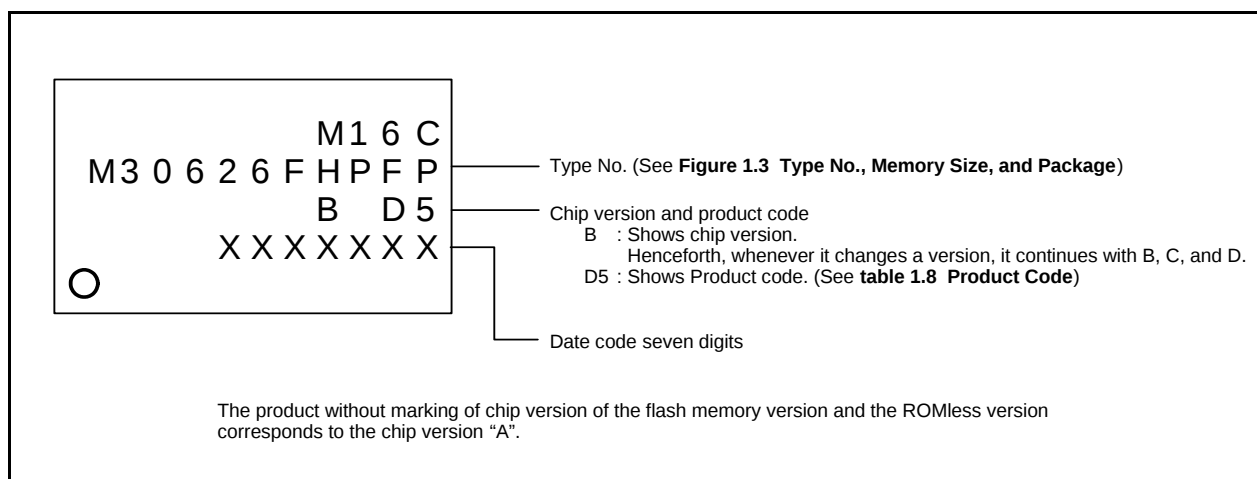
**Figure 1.4 Marking Diagram of Flash Memory version and ROM-less version for M16C/62P (Top View)**

Table 1.10 Pin Characteristics for 128-Pin Package (1)

Pin No.	Control Pin	Port	Interrupt Pin	Timer Pin	UART Pin	Analog Pin	Bus Control Pin
1	VREF						
2	AVCC						
3		P9_7			SIN4	ADTRG	
4		P9_6			SOUT4	ANEX1	
5		P9_5			CLK4	ANEX0	
6		P9_4		TB4IN		DA1	
7		P9_3		TB3IN		DA0	
8		P9_2		TB2IN	SOUT3		
9		P9_1		TB1IN	SIN3		
10		P9_0		TB0IN	CLK3		
11		P14_1					
12		P14_0					
13	BYTE						
14	CNVSS						
15	XCIN	P8_7					
16	XCOUT	P8_6					
17	RESET						
18	XOUT						
19	VSS						
20	XIN						
21	VCC1						
22		P8_5	NMI				
23		P8_4	INT2	ZP			
24		P8_3	INT1				
25		P8_2	INT0				
26		P8_1		TA4IN/U			
27		P8_0		TA4OUT/U			
28		P7_7		TA3IN			
29		P7_6		TA3OUT			
30		P7_5		TA2IN/W			
31		P7_4		TA2OUT/W			
32		P7_3		TA1IN/V	CTS2/RTS2		
33		P7_2		TA1OUT/V	CLK2		
34		P7_1		TA0IN/TB5IN	RXD2/SCL2		
35		P7_0		TA0OUT	TXD2/SDA2		
36		P6_7			TXD1/SDA1		
37	VCC1						
38		P6_6			RXD1/SCL1		
39	VSS						
40		P6_5			CLK1		
41		P6_4			CTS1/RTS1/CTS0/CLKS1		
42		P6_3			TXD0/SDA0		
43		P6_2			RXD0/SCL0		
44		P6_1			CLK0		
45		P6_0			CTS0/RTS0		
46		P13_7					
47		P13_6					
48		P13_5					
49		P13_4					
50		P5_7					RDY/CLKOUT

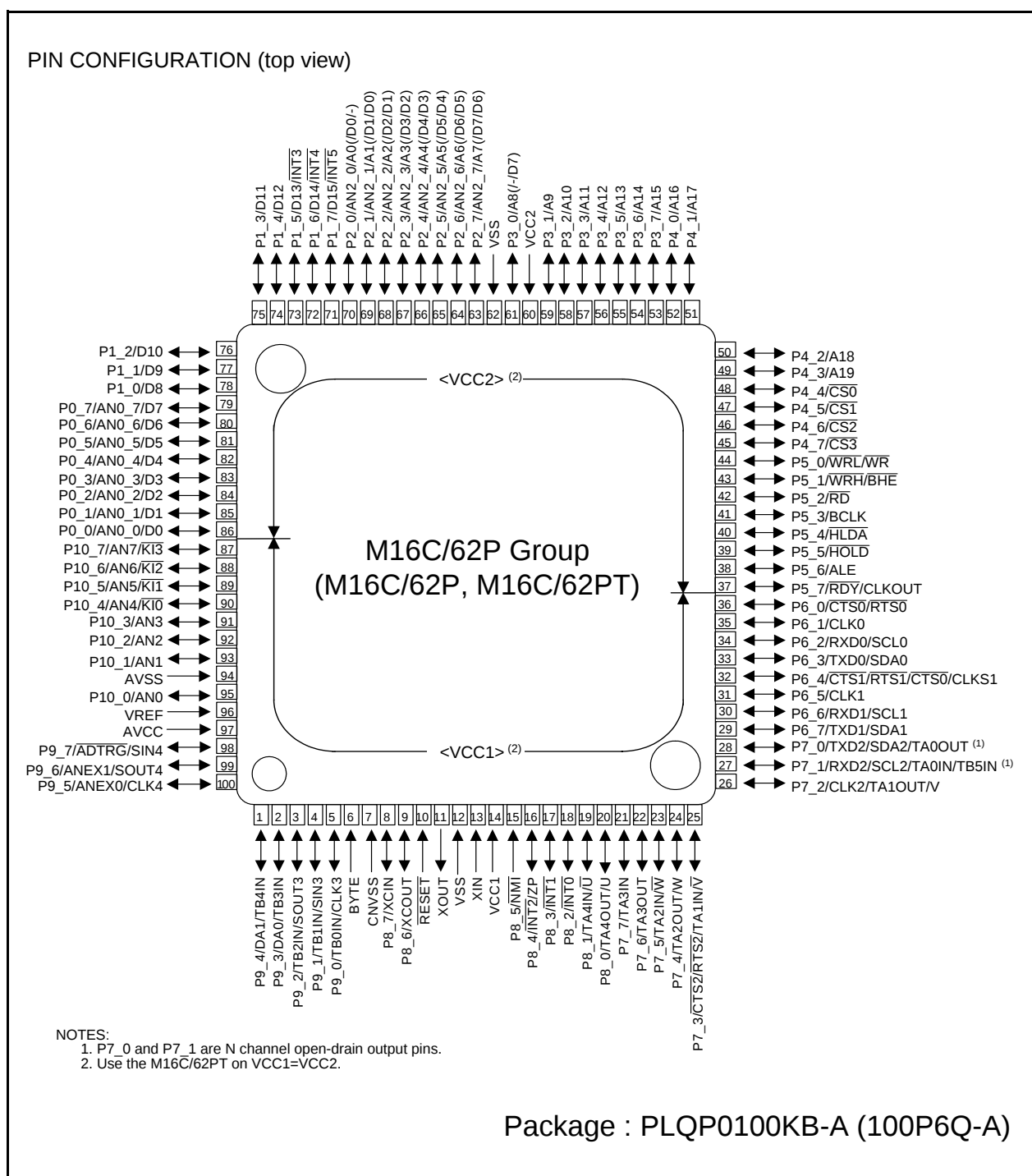


Figure 1.8 Pin Configuration (Top View)

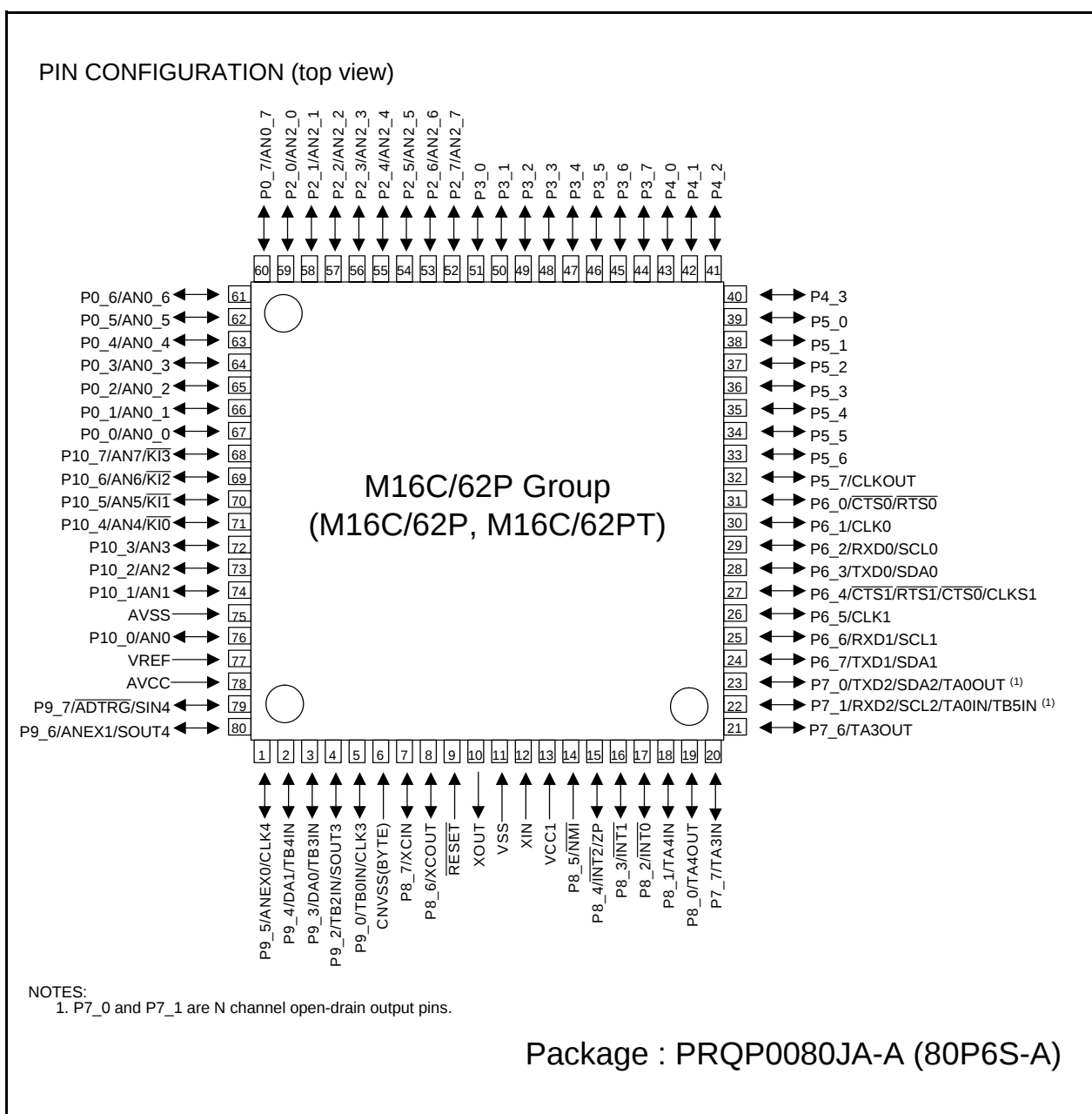


Figure 1.9 Pin Configuration (Top View)

Table 1.19 Pin Description (100-pin and 128-pin Version) (3)

Signal Name	Pin Name	I/O Type	Power Supply ⁽¹⁾	Description
Reference voltage input	VREF	I	VCC1	Applies the reference voltage for the A/D converter and D/A converter.
A/D converter	AN0 to AN7, AN0_0 to AN0_7, AN2_0 to AN2_7	I	VCC1	Analog input pins for the A/D converter.
	ADTRG	I	VCC1	This is an A/D trigger input pin.
	ANEX0	I/O	VCC1	This is the extended analog input pin for the A/D converter, and is the output in external op-amp connection mode.
	ANEX1	I	VCC1	This is the extended analog input pin for the A/D converter.
D/A converter	DA0, DA1	O	VCC1	This is the output pin for the D/A converter.
I/O port	P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P12_0 to P12_7 (2), P13_0 to P13_7 (2)	I/O	VCC2	8-bit I/O ports in CMOS, having a direction register to select an input or output. Each pin is set as an input port or output port. An input port can be set for a pull-up or for no pull-up in 4-bit unit by program.
	P6_0 to P6_7, P7_0 to P7_7, P9_0 to P9_7, P10_0 to P10_7, P11_0 to P11_7 (2)	I/O	VCC1	8-bit I/O ports having equivalent functions to P0. (however, output of P7_0 and P7_1 for the N-channel open drain output.)
	P8_0 to P8_4, P8_6, P8_7, P14_0, P14_1(2)	I/O	VCC1	I/O ports having equivalent functions to P0.
Input port	P8_5	I	VCC1	Input pin for the $\overline{\text{NMI}}$ interrupt. Pin states can be read by the P8_5 bit in the P8 register.

I : Input O : Output I/O : Input and output

NOTES:

1. When use VCC1 > VCC2, contacts due to some points or restrictions to be checked.
2. Ports P11 to P14 in M16C/62P (100-pin version) and M16C/62PT (100-pin version) cannot be used.

2.8.8 Stack Pointer Select Flag (U Flag)

ISP is selected when the U flag is “0”; USP is selected when the U flag is “1”.

The U flag is cleared to “0” when a hardware interrupt request is accepted or an INT instruction for software interrupt Nos. 0 to 31 is executed.

2.8.9 Processor Interrupt Priority Level (IPL)

IPL is configured with three bits, for specification of up to eight processor interrupt priority levels from level 0 to level 7.

If a requested interrupt has priority greater than IPL, the interrupt is enabled.

2.8.10 Reserved Area

When write to this bit, write “0”. When read, its content is indeterminate.

Table 4.4 SFR Information (4) ⁽¹⁾

Address	Register	Symbol	After Reset
0340h	Timer B3, 4, 5 Count Start Flag	TBSR	000XXXXb
0341h			
0342h	Timer A1-1 Register	TA11	XXh
0343h			XXh
0344h	Timer A2-1 Register	TA21	XXh
0345h			XXh
0346h	Timer A4-1 Register	TA41	XXh
0347h			XXh
0348h	Three-Phase PWM Control Register 0	INVC0	00h
0349h	Three-Phase PWM Control Register 1	INVC1	00h
034Ah	Three-Phase Output Buffer Register 0	IDB0	00h
034Bh	Three-Phase Output Buffer Register 1	IDB1	00h
034Ch	Dead Time Timer	DTT	XXh
034Dh	Timer B2 Interrupt Occurrence Frequency Set Counter	ICTB2	XXh
034Eh			
034Fh			
0350h	Timer B3 Register	TB3	XXh
0351h			XXh
0352h	Timer B4 Register	TB4	XXh
0353h			XXh
0354h	Timer B5 Register	TB5	XXh
0355h			XXh
0356h			
0357h			
0358h			
0359h			
035Ah			
035Bh	Timer B3 Mode Register	TB3MR	00XX0000b
035Ch	Timer B4 Mode Register	TB4MR	00XX0000b
035Dh	Timer B5 Mode Register	TB5MR	00XX0000b
035Eh	Interrupt Factor Select Register 2	IFSR2A	00XXXXXXb
035Fh	Interrupt Factor Select Register	IFSR	00h
0360h	SI/O3 Transmit/Receive Register	S3TRR	XXh
0361h			
0362h	SI/O3 Control Register	S3C	01000000b
0363h	SI/O3 Bit Rate Generator	S3BRG	XXh
0364h	SI/O4 Transmit/Receive Register	S4TRR	XXh
0365h			
0366h	SI/O4 Control Register	S4C	01000000b
0367h	SI/O4 Bit Rate Generator	S4BRG	XXh
0368h			
0369h			
036Ah			
036Bh			
036Ch	UART0 Special Mode Register 4	U0SMR4	00h
036Dh	UART0 Special Mode Register 3	U0SMR3	000X0X0Xb
036Eh	UART0 Special Mode Register 2	U0SMR2	X0000000b
036Fh	UART0 Special Mode Register	U0SMR	X0000000b
0370h	UART1 Special Mode Register 4	U1SMR4	00h
0371h	UART1 Special Mode Register 3	U1SMR3	000X0X0Xb
0372h	UART1 Special Mode Register 2	U1SMR2	X0000000b
0373h	UART1 Special Mode Register	U1SMR	X0000000b
0374h	UART2 Special Mode Register 4	U2SMR4	00h
0375h	UART2 Special Mode Register 3	U2SMR3	000X0X0Xb
0376h	UART2 Special Mode Register 2	U2SMR2	X0000000b
0377h	UART2 Special Mode Register	U2SMR	X0000000b
0378h	UART2 Transmit/Receive Mode Register	U2MR	00h
0379h	UART2 Bit Rate Generator	U2BRG	XXh
037Ah	UART2 Transmit Buffer Register	U2TB	XXh
037Bh			XXh
037Ch	UART2 Transmit/Receive Control Register 0	U2C0	00001000b
037Dh	UART2 Transmit/Receive Control Register 1	U2C1	00000010b
037Eh	UART2 Receive Buffer Register	U2RB	XXh
037Fh			XXh

NOTES:

- The blank areas are reserved and cannot be accessed by users.

X : Nothing is mapped to this bit

5. Electrical Characteristics

5.1 Electrical Characteristics (M16C/62P)

Table 5.1 Absolute Maximum Ratings

Symbol	Parameter		Condition	Rated Value	Unit
V _{CC1} , V _{CC2}	Supply Voltage		V _{CC1} =AV _{CC}	–0.3 to 6.5	V
V _{CC2}	Supply Voltage		V _{CC2}	–0.3 to V _{CC1} +0.1	V
AV _{CC}	Analog Supply Voltage		V _{CC1} =AV _{CC}	–0.3 to 6.5	V
V _I	Input Voltage	RESET, CNVSS, BYTE, P6_0 to P6_7, P7_2 to P7_7, P8_0 to P8_7, P9_0 to P9_7, P10_0 to P10_7, P11_0 to P11_7, P14_0, P14_1, VREF, XIN		–0.3 to V _{CC1} +0.3 ⁽¹⁾	V
		P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P12_0 to P12_7, P13_0 to P13_7		–0.3 to V _{CC2} +0.3 ⁽¹⁾	V
		P7_0, P7_1		–0.3 to 6.5	V
V _O	Output Voltage	P6_0 to P6_7, P7_2 to P7_7, P8_0 to P8_4, P8_6, P8_7, P9_0 to P9_7, P10_0 to P10_7, P11_0 to P11_7, P14_0, P14_1, XOUT		–0.3 to V _{CC1} +0.3 ⁽¹⁾	V
		P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P12_0 to P12_7, P13_0 to P13_7		–0.3 to V _{CC2} +0.3 ⁽¹⁾	V
		P7_0, P7_1		–0.3 to 6.5	V
P _d	Power Dissipation		–40°C<T _{opr} ≤85°C	300	mW
T _{opr}	Operating Ambient Temperature	When the Microcomputer is Operating		–20 to 85 / –40 to 85	°C
		Flash Program Erase		0 to 60	
T _{stg}	Storage Temperature			–65 to 150	°C

NOTES:

1. There is no external connections for port P1_0 to P1_7, P4_4 to P4_7, P7_2 to P7_5 and P9_1 in 80-pin version.

Table 5.9 Low Voltage Detection Circuit Electrical Characteristics

Symbol	Parameter	Measuring Condition	Standard			Unit
			Min.	Typ.	Max.	
V _{det4}	Low Voltage Detection Voltage ⁽¹⁾	V _{CC1} =0.8V to 5.5V	3.3	3.8	4.4	V
V _{det3}	Reset Level Detection Voltage ^(1, 2)		2.2	2.8	3.6	V
V _{det4} -V _{det3}	Electric potential difference of Low Voltage Detection and Reset Level Detection		0.3			V
V _{det3s}	Low Voltage Reset Retention Voltage				0.8	V
V _{det3r}	Low Voltage Reset Release Voltage ⁽³⁾		2.2	2.9	4.0	V

NOTES:

1. V_{det4} > V_{det3}.
2. Where reset level detection voltage is less than 2.7 V, if the supply power voltage is greater than the reset level detection voltage, the microcomputer operates with f(BCLK) ≤ 10MHz.
3. V_{det3r} > V_{det3} is not guaranteed.
4. The voltage detection circuit is designed to use when V_{CC1} is set to 5V.

Table 5.10 Power Supply Circuit Timing Characteristics

Symbol	Parameter	Measuring Condition	Standard			Unit
			Min.	Typ.	Max.	
t _d (P-R)	Time for Internal Power Supply Stabilization During Powering-On	V _{CC1} =2.7V to 5.5V			2	ms
t _d (R-S)	STOP Release Time				150	μs
t _d (W-S)	Low Power Dissipation Mode Wait Mode Release Time				150	μs
t _d (S-R)	Brown-out Detection Reset (Hardware Reset 2) Release Wait Time	V _{CC1} =V _{det3r} to 5.5V		6 ⁽¹⁾	20	ms
t _d (E-A)	Low Voltage Detection Circuit Operation Start Time	V _{CC1} =2.7V to 5.5V			20	μs

NOTES:

1. When V_{CC1} = 5V.

$$V_{CC1}=V_{CC2}=5V$$

Timing Requirements

($V_{CC1} = V_{CC2} = 5V$, $V_{SS} = 0V$, at $T_{opr} = -20$ to $85^{\circ}C$ / -40 to $85^{\circ}C$ unless otherwise specified)

Table 5.13 External Clock Input (XIN input) ⁽¹⁾

Symbol	Parameter	Standard		Unit
		Min.	Max.	
t_c	External Clock Input Cycle Time	62.5		ns
$t_{w(H)}$	External Clock Input HIGH Pulse Width	25		ns
$t_{w(L)}$	External Clock Input LOW Pulse Width	25		ns
t_r	External Clock Rise Time		15	ns
t_f	External Clock Fall Time		15	ns

NOTES:

1. The condition is $V_{CC1}=V_{CC2}=3.0$ to $5.0V$.

Table 5.14 Memory Expansion Mode and Microprocessor Mode

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{ac1(RD-DB)}$	Data Input Access Time (for setting with no wait)		(NOTE 1)	ns
$t_{ac2(RD-DB)}$	Data Input Access Time (for setting with wait)		(NOTE 2)	ns
$t_{ac3(RD-DB)}$	Data Input Access Time (when accessing multiplex bus area)		(NOTE 3)	ns
$t_{su(DB-RD)}$	Data Input Setup Time	40		ns
$t_{su(RDY-BCLK)}$	RDY Input Setup Time	30		ns
$t_{su(HOLD-BCLK)}$	HOLD Input Setup Time	40		ns
$t_h(RD-DB)$	Data Input Hold Time	0		ns
$t_h(BCLK-RDY)$	RDY Input Hold Time	0		ns
$t_h(BCLK-HOLD)$	HOLD Input Hold Time	0		ns

NOTES:

1. Calculated according to the BCLK frequency as follows:

$$\frac{0.5 \times 10^9}{f(BCLK)} - 45 [ns]$$

2. Calculated according to the BCLK frequency as follows:

$$\frac{(n-0.5) \times 10^9}{f(BCLK)} - 45 [ns] \quad n \text{ is "2" for 1-wait setting, "3" for 2-wait setting and "4" for 3-wait setting.}$$

3. Calculated according to the BCLK frequency as follows:

$$\frac{(n-0.5) \times 10^9}{f(BCLK)} - 45 [ns] \quad n \text{ is "2" for 2-wait setting, "3" for 3-wait setting.}$$

$$V_{CC1}=V_{CC2}=5V$$

Timing Requirements

($V_{CC1} = V_{CC2} = 5V$, $V_{SS} = 0V$, at $T_{opr} = -20$ to $85^{\circ}C$ / -40 to $85^{\circ}C$ unless otherwise specified)

Table 5.15 Timer A Input (Counter Input in Event Counter Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TA)}$	TAiIN Input Cycle Time	100		ns
$t_{w(TAH)}$	TAiIN Input HIGH Pulse Width	40		ns
$t_{w(TAL)}$	TAiIN Input LOW Pulse Width	40		ns

Table 5.16 Timer A Input (Gating Input in Timer Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TA)}$	TAiIN Input Cycle Time	400		ns
$t_{w(TAH)}$	TAiIN Input HIGH Pulse Width	200		ns
$t_{w(TAL)}$	TAiIN Input LOW Pulse Width	200		ns

Table 5.17 Timer A Input (External Trigger Input in One-shot Timer Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TA)}$	TAiIN Input Cycle Time	200		ns
$t_{w(TAH)}$	TAiIN Input HIGH Pulse Width	100		ns
$t_{w(TAL)}$	TAiIN Input LOW Pulse Width	100		ns

Table 5.18 Timer A Input (External Trigger Input in Pulse Width Modulation Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{w(TAH)}$	TAiIN Input HIGH Pulse Width	100		ns
$t_{w(TAL)}$	TAiIN Input LOW Pulse Width	100		ns

Table 5.19 Timer A Input (Counter Increment/Decrement Input in Event Counter Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(UP)}$	TAiOUT Input Cycle Time	2000		ns
$t_{w(UPH)}$	TAiOUT Input HIGH Pulse Width	1000		ns
$t_{w(UPL)}$	TAiOUT Input LOW Pulse Width	1000		ns
$t_{su(UP-TIN)}$	TAiOUT Input Setup Time	400		ns
$t_{h(TIN-UP)}$	TAiOUT Input Hold Time	400		ns

Table 5.20 Timer A Input (Two-phase Pulse Input in Event Counter Mode)

Symbol	Parameter	Standard		Unit
		Min.	Max.	
$t_{c(TA)}$	TAiIN Input Cycle Time	800		ns
$t_{su(TAIN-TAOUT)}$	TAiOUT Input Setup Time	200		ns
$t_{su(TAOUT-TAIN)}$	TAiIN Input Setup Time	200		ns

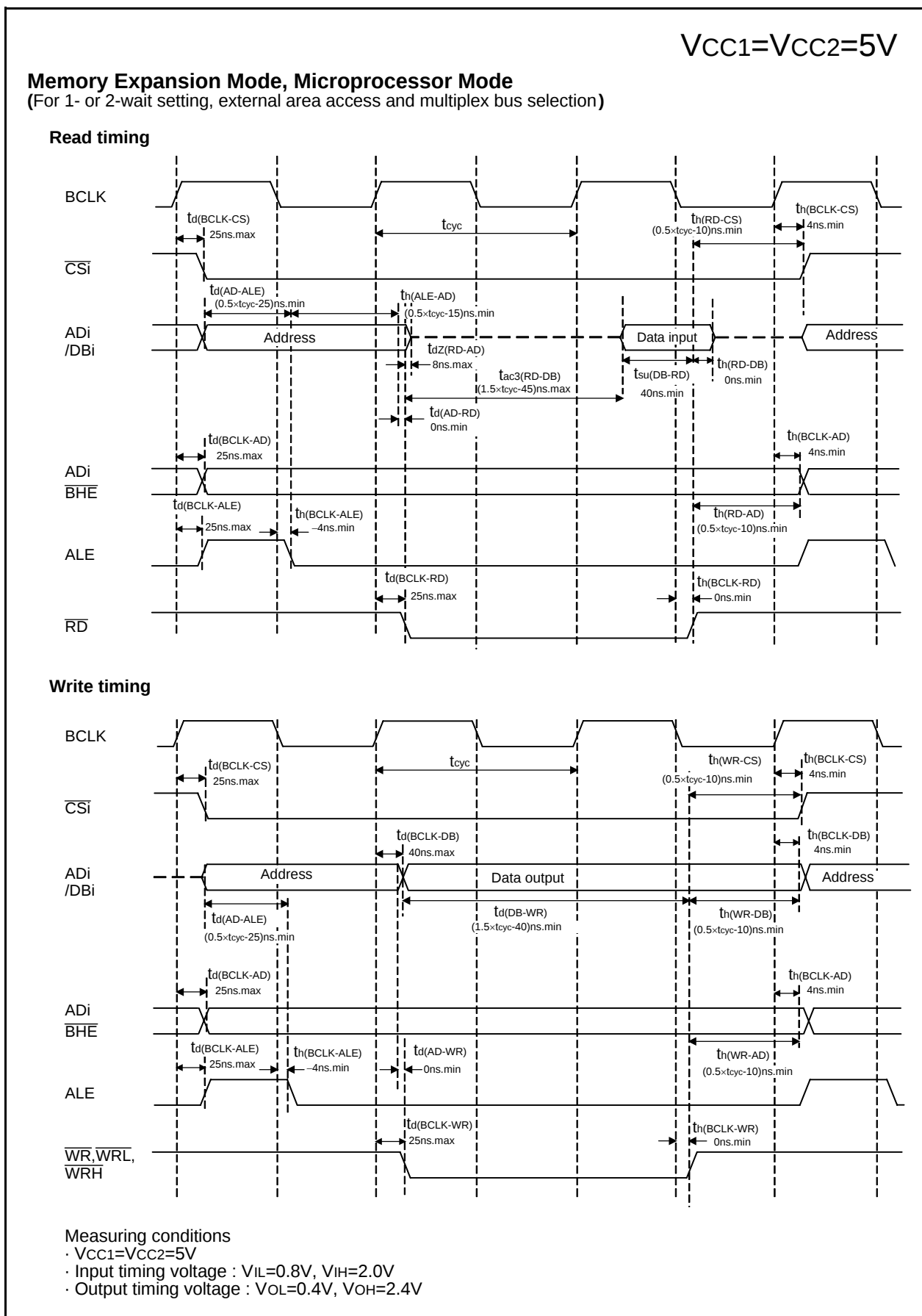


Figure 5.10 Timing Diagram (8)

Table 5.31 Electrical Characteristics (2) ⁽¹⁾

Symbol	Parameter		Measuring Condition		Standard			Unit
					Min.	Typ.	Max.	
Icc	Power Supply Current (Vcc1=Vcc2=2.7V to 3.6V)	In single-chip mode, the output pins are open and other pins are Vss	Mask ROM	f(BCLK)=10MHz No division		8	11	mA
				No division, On-chip oscillation		1		mA
			Flash Memory	f(BCLK)=10MHz, No division		8	13	mA
				No division, On-chip oscillation		1.8		mA
			Flash Memory Program	f(BCLK)=10MHz, VCC1=3.0V		12		mA
			Flash Memory Erase	f(BCLK)=10MHz, VCC1=3.0V		22		mA
			Mask ROM	f(XCIN)=32kHz Low power dissipation mode, ROM ⁽³⁾		25		μA
			Flash Memory	f(BCLK)=32kHz Low power dissipation mode, RAM ⁽³⁾		25		μA
				f(BCLK)=32kHz Low power dissipation mode, Flash Memory ⁽³⁾		420		μA
				On-chip oscillation, Wait mode		45		μA
				Mask ROM Flash Memory	f(BCLK)=32kHz Wait mode ⁽²⁾ , Oscillation capability High		6.0	
			f(BCLK)=32kHz Wait mode ⁽²⁾ , Oscillation capability Low			1.8		μA
			Stop mode Topr =25°C			0.7	3.0	μA
Idet4	Low Voltage Detection Dissipation Current ⁽⁴⁾					0.6	4	μA
Idet3	Reset Area Detection Dissipation Current ⁽⁴⁾					0.4	2	μA

NOTES:

1. Referenced to V_{CC1}=V_{CC2}=2.7 to 3.3V, V_{SS} = 0V at T_{opr} = -20 to 85°C / -40 to 85°C, f(BCLK)=10MHz unless otherwise specified.
2. With one timer operated using fC32.
3. This indicates the memory in which the program to be executed exists.
4. I_{det} is dissipation current when the following bit is set to "1" (detection circuit enabled).
I_{det4}: VC27 bit in the VCR2 register
I_{det3}: VC26 bit in the VCR2 register

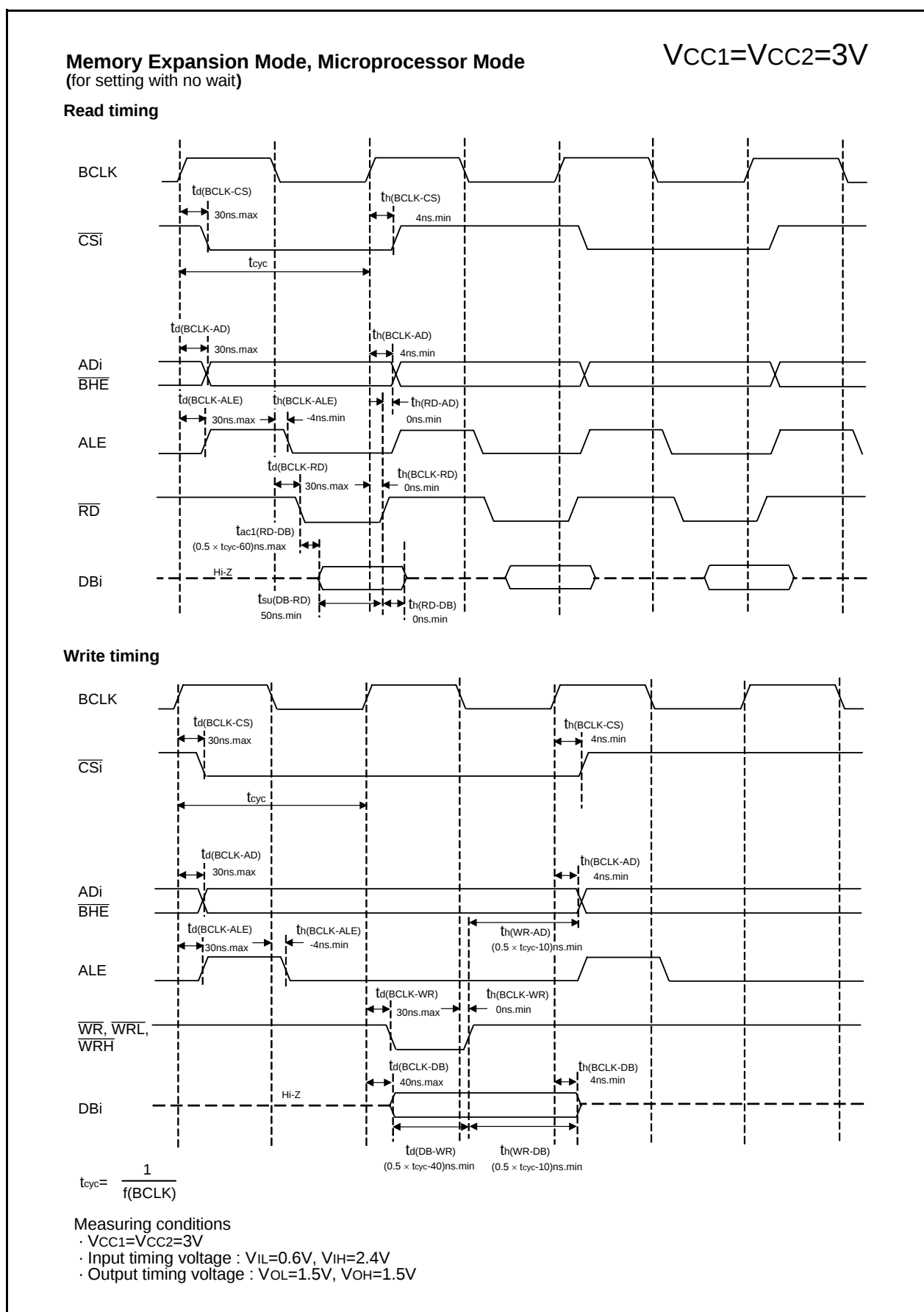


Figure 5.16 Timing Diagram (4)

5.2 Electrical Characteristics (M16C/62PT)

Table 5.49 Absolute Maximum Ratings

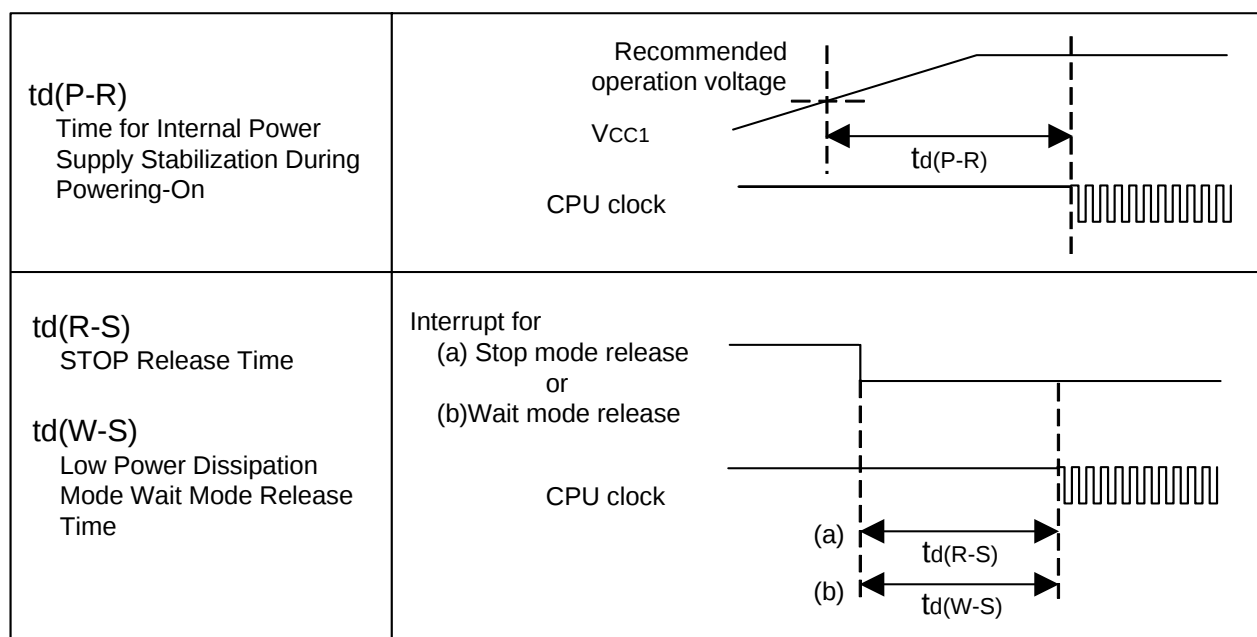
Symbol	Parameter		Condition	Rated Value	Unit
V _{CC1} , V _{CC2}	Supply Voltage		V _{CC1} =V _{CC2} =AV _{CC}	−0.3 to 6.5	V
AV _{CC}	Analog Supply Voltage		V _{CC1} =V _{CC2} =AV _{CC}	−0.3 to 6.5	V
V _I	Input Voltage	RESET, CNVSS, BYTE, P6_0 to P6_7, P7_2 to P7_7, P8_0 to P8_7, P9_0 to P9_7, P10_0 to P10_7, P11_0 to P11_7, P14_0, P14_1, VREF, XIN		−0.3 to V _{CC1} +0.3 ⁽¹⁾	V
		P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P12_0 to P12_7, P13_0 to P13_7		−0.3 to V _{CC2} +0.3 ⁽¹⁾	V
		P7_0, P7_1		−0.3 to 6.5	V
V _O	Output Voltage	P6_0 to P6_7, P7_2 to P7_7, P8_0 to P8_4, P8_6, P8_7, P9_0 to P9_7, P10_0 to P10_7, P11_0 to P11_7, P14_0, P14_1, XOUT		−0.3 to V _{CC1} +0.3 ⁽¹⁾	V
		P0_0 to P0_7, P1_0 to P1_7, P2_0 to P2_7, P3_0 to P3_7, P4_0 to P4_7, P5_0 to P5_7, P12_0 to P12_7, P13_0 to P13_7		−0.3 to V _{CC2} +0.3 ⁽¹⁾	V
		P7_0, P7_1		−0.3 to 6.5	V
P _d	Power Dissipation		−40°C<T _{opr} ≤85°C	300	mW
			85°C<T _{opr} ≤125°C	200	
T _{opr}	Operating Ambient Temperature	When the Microcomputer is Operating		−40 to 85 / −40 to 125 ⁽²⁾	°C
		Flash Program Erase		0 to 60	
T _{stg}	Storage Temperature			−65 to 150	°C

NOTES:

1. There is no external connections for port P1_0 to P1_7, P4_4 to P4_7, P7_2 to P7_5 and P9_1 in 80-pin version.
2. T version = −40 to 85 °C, V version= −40 to 125 °C.

Table 5.56 Power Supply Circuit Timing Characteristics

Symbol	Parameter	Measuring Condition	Standard			Unit
			Min.	Typ.	Max.	
$t_{d(P-R)}$	Time for Internal Power Supply Stabilization During Powering-On	$V_{CC1}=4.0V$ to $5.5V$			2	ms
$t_{d(R-S)}$	STOP Release Time				150	μs
$t_{d(W-S)}$	Low Power Dissipation Mode Wait Mode Release Time				150	μs

**Figure 5.22 Power Supply Circuit Timing Diagram**

$$V_{CC1}=V_{CC2}=5V$$

Switching Characteristics

($V_{CC1} = V_{CC2} = 5V$, $V_{SS} = 0V$, at $T_{opr} = -40$ to $85^{\circ}C$ (T version) / -40 to $125^{\circ}C$ (V version) unless otherwise specified)

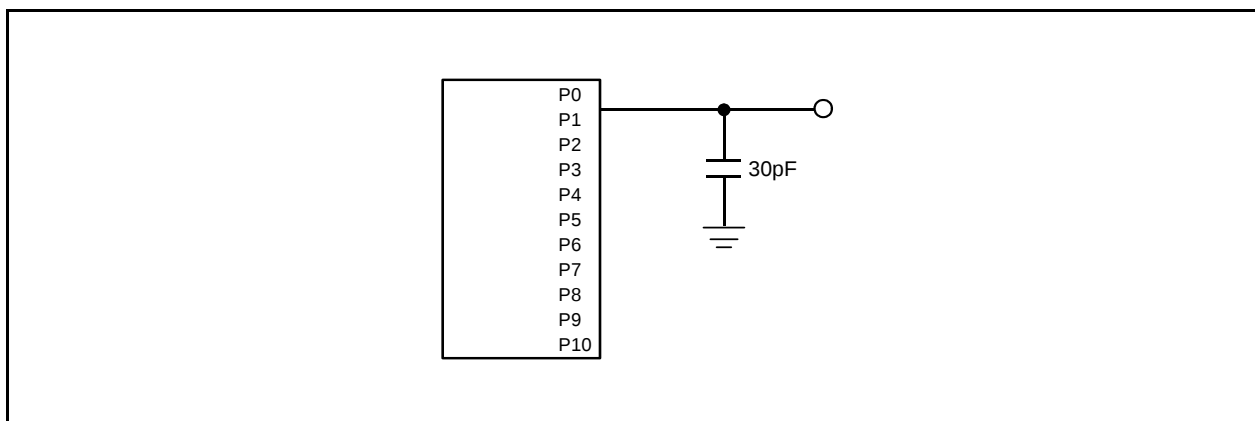


Figure 5.23 Ports P0 to P10 Measurement Circuit

Appendix 1.Package Dimensions

